

Hoseok Heo

List of Publications by Year in descending order

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15
papers

1,135
citations

687363
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docs citations

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times ranked

2734
citing authors

#	ARTICLE	IF	CITATIONS
1	Bilayer Wigner crystals in a transition metal dichalcogenide heterostructure. <i>Nature</i> , 2021, 595, 48-52.	27.8	98
2	Broken mirror symmetry in excitonic response of reconstructed domains in twisted MoSe ₂ /MoSe ₂ bilayers. <i>Nature Nanotechnology</i> , 2020, 15, 750-754.	31.5	106
3	Atomically thin three-dimensional membranes of van der Waals semiconductors by wafer-scale growth. <i>Science Advances</i> , 2019, 5, eaaw3180.	10.3	22
4	Liquid Salt Transport Growth of Single Crystals of the Layered Dichalcogenides MoS ₂ and WS ₂ . <i>Crystal Growth and Design</i> , 2019, 19, 5762-5767.	3.0	16
5	Directly Assembled 3D Molybdenum Disulfide on Silicon Wafer for Efficient Photoelectrochemical Water Reduction. <i>Advanced Sustainable Systems</i> , 2018, 2, 1700142.	5.3	36
6	Frankâ€“van der Merwe Growth versus Volmerâ€“Weber Growth in Successive Stacking of a Fewâ€“Layer Bi ₂ Te ₃ /Sb ₂ Te ₃ by van der Waals Heteroepitaxy: The Critical Roles of Finite Latticeâ€“Mismatch with Seed Substrates. <i>Advanced Electronic Materials</i> , 2017, 3, 1600375.	5.1	25
7	Thermoelectric materials by using two-dimensional materials with negative correlation between electrical and thermal conductivity. <i>Nature Communications</i> , 2016, 7, 12011.	12.8	173
8	Vapor Transport Synthesis of Two-Dimensional SnS ₂ Nanocrystals Using a SnS ₂ Precursor Obtained from the Sulfurization of SnO ₂ . <i>Crystal Growth and Design</i> , 2016, 16, 3884-3889.	3.0	23
9	Rotationâ€“Misfitâ€“Free Heteroepitaxial Stacking and Stitching Growth of Hexagonal Transitionâ€“Metal Dichalcogenide Monolayers by Nucleation Kinetics Controls. <i>Advanced Materials</i> , 2015, 27, 3803-3810.	21.0	113
10	2D Materials: Rotationâ€“Misfitâ€“Free Heteroepitaxial Stacking and Stitching Growth of Hexagonal Transitionâ€“Metal Dichalcogenide Monolayers by Nucleation Kinetics Controls (Adv. Mater. 25/2015). <i>Advanced Materials</i> , 2015, 27, 3839-3839.	21.0	2
11	Interlayer orientation-dependent light absorption and emission in monolayer semiconductor stacks. <i>Nature Communications</i> , 2015, 6, 7372.	12.8	154
12	Deterministic Two-Dimensional Polymorphism Growth of Hexagonal <i>n</i> -Type SnS ₂ and Orthorhombic <i>p</i> -Type SnS Crystals. <i>Nano Letters</i> , 2015, 15, 3703-3708.	9.1	289
13	Tunable Catalytic Alloying Eliminates Stacking Faults in Compound Semiconductor Nanowires. <i>Nano Letters</i> , 2012, 12, 855-860.	9.1	18
14	Kinetics-driven high power Li-ion battery with a-Si/NiSi _x core-shell nanowire anodes. <i>Nature</i> , 2011, , .	0	
15	Kinetics-driven high power Li-ion battery with a-Si/NiSix core-shell nanowire anodes. <i>Chemical Science</i> , 2011, 2, 1090.	7.4	60